Preliminary Data Sheet PD-2.604 rev. A 12/00

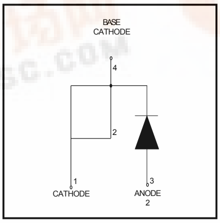
International
IOR Rectifier

HFA30PB120

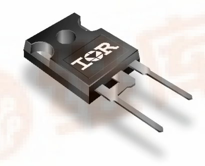
HEXFRED™ Ultrafast, Soft Recovery Diode

Features
- Ultrafast Recovery
- Ultrasoft Recovery
- Very Low I_{RRM}
- Very Low Q_{rr}
- Specified at Operating Conditions

Benefits
- Reduced RFI and EMI
- Reduced Power Loss in Diode and Switching Transistor
- Higher Frequency Operation
- Reduced Snubbing
- Reduced Parts Count



V_R = 1200V
V_F(typ.)* = 2.4V
$I_{F(AV)}$ = 30A
Q_{rr} (typ.)= 490nC
I_{RRM}(typ.) = 8.1A
t_{rr}(typ.) = 37ns
$di_{(rec)M}/dt$ (typ.)* = 130A/μs



TO-247AC (Modified)

Description
International Rectifier's HFA30PB120 is a state of the art ultra fast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 volts and 30 amps continuous current, the HFA30PB120 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultra fast recovery time, the HEXFRED product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA30PB120 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

Absolute Maximum Ratings

	Parameter	Max.	Units
V_R	Cathode-to-Anode Voltage	1200	V
I_F @ T_C = 100°C	Continuous Forward Current	30	A
I_{FSM}	Single Pulse Forward Current	120	
I_{FRM}	Maximum Repetitive Forward Current	90	
P_D @ T_C = 25°C	Maximum Power Dissipation		W
P_D @ T_C = 100°C	Maximum Power Dissipation		
T_J	Operating Junction and	-55 to +150	°C
T_{STG}	Storage Temperature Range		

* 125°C

Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Test Conditions
V_{BR}	Cathode Anode Breakdown Voltage	1200	—	—	V	I_R = 100µA
V_{FM}	Max Forward Voltage	—	2.5	3.0	V	I_F = 16A
		—	3.2	3.93		I_F = 32A See Fig. 1
		—	2.3	2.7		I_F = 16A, T_J = 125°C
I_{RM}	Max Reverse Leakage Current	—	0.75	20	µA	V_R = V_R Rated See Fig. 2
		—	375	2000		T_J = 125°C, V_R = 0.8 x V_R Rated
C_T	Junction Capacitance	—	27	40	pF	V_R = 200V See Fig. 3
L_S	Series Inductance	—	8.0	—	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Test Conditions	
t_{rr}	Reverse Recovery Time	—	30	—	ns	I_F = 1.0A, di_f/dt = 200A/µs, V_R = 30V	
t_{rr1}	See Fig. 5, 10	—	90	135		T_J = 25°C	I_F = 16A
t_{rr2}		—	164	245		T_J = 125°C	
I_{RRM1}	Peak Recovery Current	—	5.8	10	A	T_J = 25°C	V_R = 200V
I_{RRM2}	See Fig. 6	—	8.3	15		T_J = 125°C	
Q_{rr1}	Reverse Recovery Charge	—	260	675	nC	T_J = 25°C	di_f/dt = 200A/µs
Q_{rr2}	See Fig. 7	—	680	1838		T_J = 125°C	
$di_{(rec)M}/dt1$	Peak Rate of Fall of Recovery Current	—	120	—	A/µs	T_J = 25°C	
$di_{(rec)M}/dt2$	During t_b See Fig. 8	—	76	—		T_J = 125°C	

Thermal - Mechanical Characteristics

	Parameter	Min.	Typ.	Max.	Units
T_{lead}②	Lead Temperature	—	—	300	°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	—	—	0.83	K/W
$R_{\theta JA}$③	Thermal Resistance, Junction to Ambient	—	—	80	
$R_{\theta CS}$④	Thermal Resistance, Case to Heat Sink	—	0.50	—	
Wt	Weight	—	2.0	—	g
		—	0.07	—	(oz)
	Mounting Torque	6.0	—	12	Kg-cm
		5.0	—	10	lbf•in

① L=100µH, duty cycle limited by max T_J
② 0.063 in. from Case (1.6mm) for 10 sec
③ Typical Socket Mount
④ Mounting Surface, Flat, Smooth and Greased

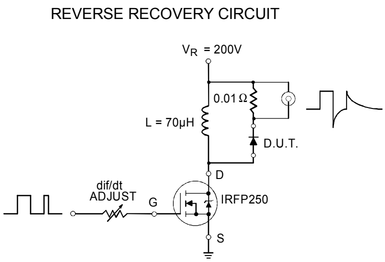
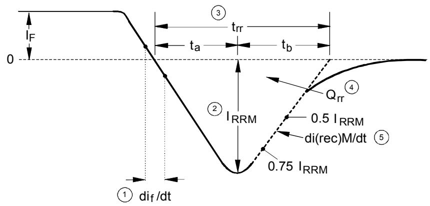


Fig. 9 - Reverse Recovery Parameter Test Circuit

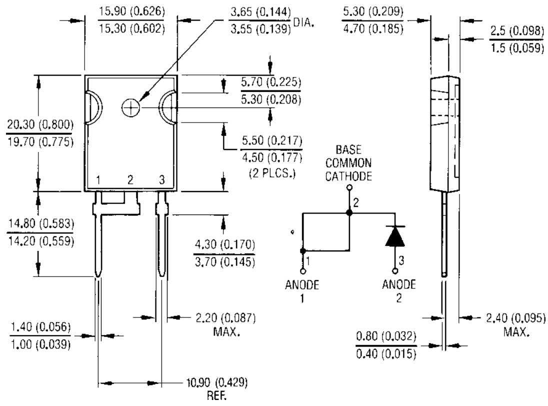


1. di_f/dt - Rate of change of current through zero crossing
2. I_{RRM} - Peak reverse recovery current
3. trr - Reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current
4. Q_{rr} - Area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

5. $di_{(rec)M}/dt$ - Peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions



Conforms to JEDEC Outline TO-247AC(Modified)
Dimensions in millimeters and inches

International Rectifier

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